

- |                         |  |
|-------------------------|--|
| 1. Record Nr.           | UNISALENTO991003382539707536   |
| Autore                  | Purkis, John   |
| Titolo                  | A preface to Wordsworth / John Purkis  |
| Pubbl/distr/stampa      | London : Longman, 1970   |
| Descrizione fisica      | 208 p. ; 21 cm   |
| Collana                 | Preface books  |
| Soggetti                | Wordsworth, William<br>Wordsworth, William   |
| Lingua di pubblicazione | Inglese  |
| Formato                 | Materiale a stampa   |
| Livello bibliografico   | Monografia   |
| 2. Record Nr.           | UNINA9910816140603321  |
| Autore                  | Kerherve Eric  |
| Titolo                  | Linearization and efficiency enhancement techniques for silicon power amplifiers : from RF to mmW // Eric Kerherve, Didier Belot   |
| Pubbl/distr/stampa      | Oxford, England : , : Academic Press, , 2015<br>©2015  |
| ISBN                    | 0-12-418681-5  |
| Descrizione fisica      | 1 online resource (163 p.)   |
| Disciplina              | 621.381325   |
| Soggetti                | Power amplifiers<br>Amplifiers, Radio frequency  |
| Lingua di pubblicazione | Inglese  |
| Formato                 | Materiale a stampa   |
| Livello bibliografico   | Monografia   |
| Note generali           | Description based upon print version of record.  |
| Nota di bibliografia    | Includes bibliographical references.   |
| Nota di contenuto       | Front Cover; Linearization and Efficiency Enhancement Techniques for Silicon Power Amplifiers; Copyright Page; Contents; List of Contributors; 1 Holistic Approaches for Power Generation, Linearization, and Radiation in CMOS; 1.1 Self-Healing Integrated |

Circuits; 1.1.1 Self-Healing mm-Wave Power Amplifier; 1.1.2 Sensing RF Power; 1.1.3 Sensing DC Current; 1.1.4 Actuating Quiescent Operating Point; 1.1.5 Data Conversion and Healing Algorithm; 1.1.6 Measurement Results; 1.2 Segmented Power Mixer for mm-Wave Transmitters; 1.2.1 Key Building Blocks; 1.2.2 Measurement Results 1.3 Distributed Active Radiation1.3.1 DAR Design Approach; 1.3.2 Architecture; 1.3.3 Measurement Results; References; 2 Cartesian Feedback with Digital Enhancement for CMOS RF Transmitter; 2.1 Introduction; 2.2 CFB Loop; 2.3 CFB Digital Part Implementation; 2.3.1 Phase Estimation; 2.3.1.1 "atan"-Based Architecture; 2.3.1.1.1 LUT-Based Architecture; 2.3.1.1.2 CORDIC-Based Architecture; 2.3.1.2 "Modulo" Function Implementation; 2.3.2 Vector Rotation; 2.3.2.1 LUT and Multipliers Solution; 2.3.2.2 CORDIC-Based Solution; 2.3.3 Subtraction; 2.3.4 Improvement of CFB CORDIC-Based Architecture 2.3.4.1 Modification of the CFB Algorithm2.3.4.2 New Architecture; 2.4 Analog Part Implementation; 2.5 Linearized Transmitter Results; 2.6 Power Consumption and Size Considerations; 2.7 Conclusion; References; 3 Transmitter Linearity and Energy Efficiency; 3.1 Introduction; 3.2 The PA Design Problem; 3.3 A Reverse Design Approach; 3.3.1 PA Operating Modes; 3.3.2 What Does "Gain" Mean When Nonlinear?; 3.3.3 Apparent Linearity: Output Signal Accuracy; 3.3.4 Stage Series Resistance; 3.4 Output Power Control; 3.5 OBO Elimination; 3.6 Stabilities: Circuit, Thermal, and Manufacturing 3.6.1 Stability of the Circuit3.6.2 Stability Over Temperature; 3.6.3 Stability Across Manufacturing; 3.7 Aging; 3.8 Categorizing C-mode Operation; 3.9 Conclusion; References; 4 mmW Doherty; 4.1 Introduction; 4.2 Doherty Amplifier; 4.2.1 Doherty Structure; 4.2.2 Nonidealities in Doherty Structure; 4.3 mmW Doherty Amplifiers; 4.3.1 Silicon Transistors in mmW Doherty Structure; 4.3.2 Passive Components in mmW Doherty Structure; 4.3.3 Other Techniques; References; 5 Reliable Power Amplifier; 5.1 Introduction; 5.2 Effect of CMOS Technology Scaling on Thermal Management 5.3 Metal Interconnects Electromigration5.4 Time-Dependent Dielectric Breakdown (TDDB); 5.5 Hot Carrier Injection; 5.5.1 DC Model; 5.5.2 RF Model; 5.6 Electrostatic Static Discharge; 5.6.1 Human Body Model; 5.6.2 Machine Model; 5.6.3 Charged Device Model; 5.6.4 ESD Protection; 5.7 Voltage Standing Wave Ratio; 5.8 Power Amplifier Design for Reliability; 5.8.1 Mission Profile Analysis; 5.9 Intrinsically Robust Design; 5.10 Self-Healing Design; 5.11 Conclusion; References; 6 Efficiency Enhancement for THz Power Amplifier; 6.1 Introduction 6.2 Power Amplifier Performance Trade-offs Toward THz Operation

---

## Sommario/riassunto

Learn how to design and linearize high performance silicon power amplifiers, improving efficiency and solving problems and trade-offs of power amplifier design

---